

STP200NF03 STB200NF03 - STB200NF03-1

N-channel 30V - 0.0032Ω - 120A - D²PAK/I²PAK/TO-220 STripFET™ III Power MOSFET

General features

| Туре | V _{DSS} | R _{DS(on)} | I _D |
|--------------|------------------|---------------------|---------------------|
| STP200NF03 | 30V | <0.0037Ω | 120A ⁽¹⁾ |
| STB200NF03 | 30V | <0.0037Ω | 120A ⁽¹⁾ |
| STB200NF03-1 | 30V | <0.0037Ω | 120A ⁽¹⁾ |

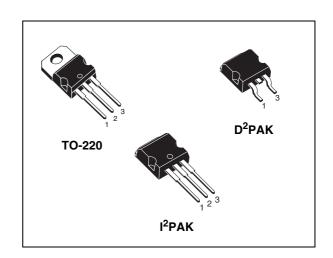
- 1. Current Limited by Package
- Standard threshold drive
- 100% avalanche tested

Description

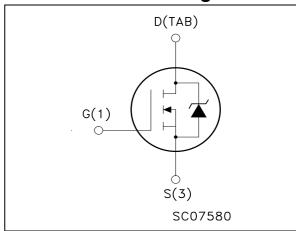
This Power MOSFET is the latest development of STMicroelectronics unique "Single Feature SizeTM" strip-based process. The resulting transistor shows extremely high packing density for low on-resistance, rugged avalanche characteristics and less critical alignment steps therefore a remarkable manufacturing reproducibility.

Applications

Switching application



Internal schematic diagram



Order codes

| Part number | Marking | Package | Packaging | |
|--------------|----------|--------------------|-------------|--|
| STB200NF03T4 | B200NF03 | D ² PAK | Tape & reel | |
| STB200NF03-1 | B200NF03 | I ² PAK | Tube | |
| STP200NF03 | P200NF03 | TO-220 | Tube | |

February 2007 Rev 4 1/18

Contents

| 1 | Electrical ratings 3 |
|---|-----------------------------|
| 2 | Electrical characteristics |
| 3 | Spice thermal model |
| 4 | Test circuit |
| 5 | Package mechanical data |
| 6 | Packaging mechanical data16 |
| 7 | Revision history |

1 Electrical ratings

Table 1. Absolute maximum ratings

| Symbol | Parameter | Value | Unit |
|--------------------------------|--|------------|------|
| V_{DS} | Drain-source voltage (V _{GS} = 0) | 30 | V |
| V _{DGR} | Drain-gate voltage (R_{GS} = 20 kΩ) | 30 | V |
| V _{GS} | Gate- source voltage | ± 20 | V |
| I _D ⁽¹⁾ | Drain current (continuous) at T _C = 25°C | 120 | А |
| I _D ⁽¹⁾ | Drain current (continuous) at T _C = 100°C | 120 | А |
| I _{DM} ⁽²⁾ | Drain current (pulsed) | 480 | А |
| P _{tot} | Total dissipation at T _C = 25°C | 300 | W |
| | Derating factor | 2.0 | W/°C |
| dv/dt ⁽³⁾ | Peak diode recovery voltage slope | 1.5 | V/ns |
| E _{AS} (4) | Single pulse avalanche energy | 1.45 | J |
| T _{stg} | Storage temperature | | |
| T _j | Max. operating junction temperature | -55 to 175 | °C |

- 1. Value limited by package
- 2. Pulse width limited by safe operating area.
- 3. $I_{SD} \leq 20A$, di/dt $\leq 400A/\mu s$, $V_{DD} \leq V_{(BR)DSS}$, $T_j \leq T_{JMAX}$
- 4. Starting $T_i = 25$ °C, $I_D = 60A$, $V_{DD} = 25V$

Table 2. Thermal data

| Rthj-case | Thermal resistance junction-case max | 0.5 | °C/W |
|----------------|---|---------------------|------|
| Rthj-amb | Thermal resistance junction-ambient max | 62.5 | °C/W |
| Rthj-pcb | Thermal resistance junction-pcb | see curve 13 and 14 | |
| T _J | Maximum lead temperature for soldering purpose ⁽¹⁾ | 300 | °C |

1. for 10 sec. 1.6mm from case

5//

2 Electrical characteristics

(T_{CASE}=25°C unless otherwise specified)

Table 3. On/off states

| Symbol | Parameter | Test conditions | Min. | Тур. | Max. | Unit |
|----------------------|--|--|------|--------|---------|--------------------------|
| V _{(BR)DSS} | Drain-source breakdown voltage | $I_D = 250 \mu A, V_{GS} = 0$ | 30 | | | V |
| I _{DSS} | Zero gate voltage drain current (V _{GS} = 0) | V_{DS} = max ratings V_{DS} = max ratings, T_{C} = 125°C | | | 1 10 | μ Α μ Α |
| I _{GSS} | Gate-body leakage current (V _{DS} = 0) | V _{GS} = ± 20V | | | ±100 | nA |
| V _{GS(th)} | Gate threshold voltage | $V_{DS} = V_{GS}, I_{D} = 250 \mu A$ | 2 | | 4 | ٧ |
| R _{DS(on)} | Static drain-source on resistance | $V_{GS} = 10V, I_D = 60A$ | | 0.0032 | 0.0036 | Ω |

Table 4. Dynamic

| Symbol | Parameter | Test conditions | Min. | Тур. | Max. | Unit |
|--|---|---|------|-----------------------|------|----------------|
| 9 _{fs} ⁽¹⁾ | Forward transconductance | V _{DS} = 15V _, I _D = 60A | | 200 | | S |
| C _{iss} C _{oss} C _{rss} | Input capacitance Output capacitance Reverse transfer capacitance | $V_{DS} = 25V, f = 1MHz,$ $V_{GS} = 0$ | | 4950 1750 280 | | pF pF pF |
| t _{d(on)} t _r t _{d(off)} t _f | Turn-on delay time Rise time Turn-off delay time Fall time | V_{DD} = 15V, I_{D} = 60A R_{G} = 4.7 Ω V_{GS} = 10V (see <i>Figure 19</i>) | | 30 195 75 60 | | ns ns ns |
| Q _g Q _{gs} Q _{gd} | Total gate charge Gate-source charge Gate-drain charge | V_{DD} = 24V, I_D = 120A, V_{GS} = 10V (see <i>Figure 20</i>) | | 113 32 41 | 140 | nC nC nC |

^{1.} Pulsed: Pulse duration = 300 μ s, duty cycle 1.5%.

Table 5. Source drain diode

| Symbol | Parameter | Test conditions | Min. | Тур. | Max. | Unit |
|--|--|--|------|----------------|------------|---------------|
| I _{SD} | Source-drain current Source-drain current (pulsed) | | | | 120 480 | A A |
| V _{SD} ⁽²⁾ | Forward on voltage | I _{SD} = 120A, V _{GS} = 0 | | | 1.3 | V |
| t _{rr} Q _{rr} I _{RRM} | Reverse recovery time Reverse recovery charge Reverse recovery current | $I_{SD} = 120A,$ $di/dt = 100A/\mu s,$ $V_{DD} = 25V, T_j = 150^{\circ}C$ (see <i>Figure 21</i>) | | 70 170 5 | | ns nC A |

^{1.} Pulse width limited by safe operating area.

^{2.} Pulsed: Pulse duration = 300 μ s, duty cycle 1.5%

2.1 Electrical characteristics (curves)

Figure 1. Safe operating area

Figure 2. Thermal impedance

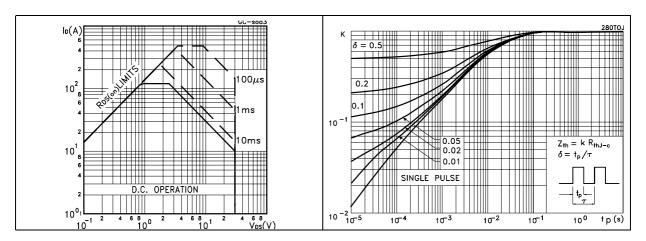


Figure 3. Output characteristics

Figure 4. Transfer characteristics

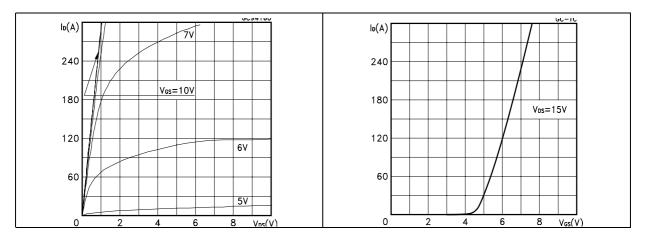


Figure 5. Transconductance

Figure 6. Static drain-source on resistance

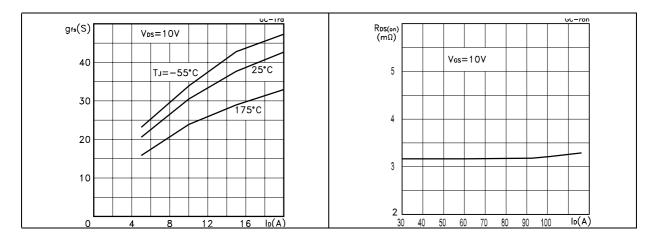


Figure 7. Gate charge vs. gate-source voltage Figure 8. Capacitance variations

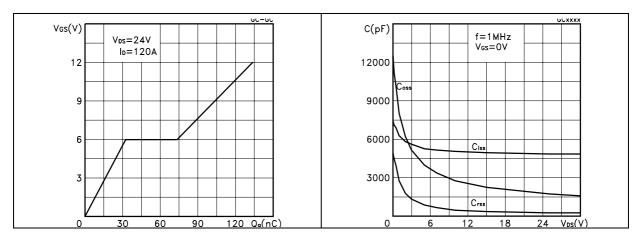


Figure 9. Normalized gate threshold voltage Figure 10. Normalized on resistance vs. vs. temperature temperature

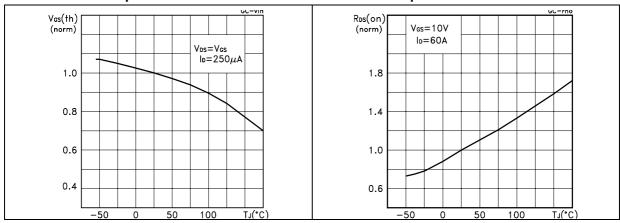
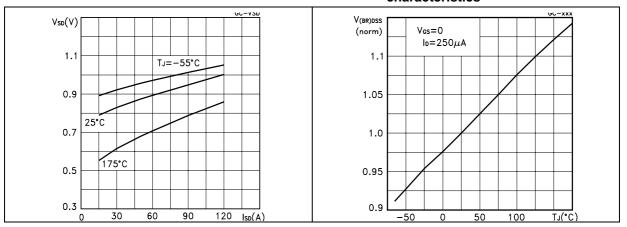


Figure 11. Normalized B_{VDSS} vs. temperature Figure 12. Source-drain diode forward characteristics



577

Figure 13. Thermal resistance rthj-a vs. PCB copper area

Figure 14. Max power dissipation vs. PCB copper area

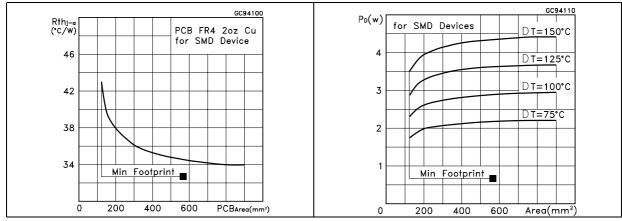


Figure 15. Power Derating vs. Tc

Figure 16. Max Id Current vs. Tc

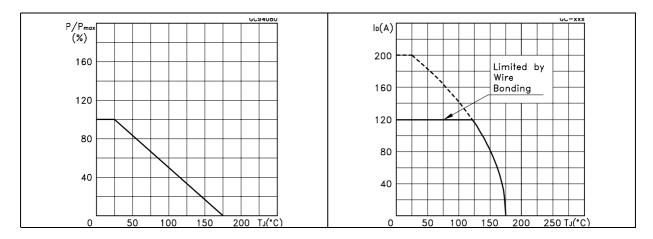
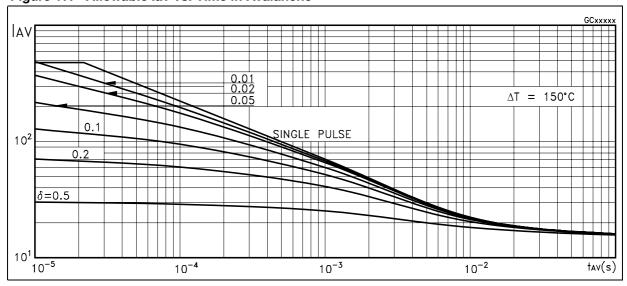


Figure 17. Allowable lav vs. Time in Avalanche



The previous curve gives the safe operating area for unclamped inductive loads, single pulse or repetitive, under the following conditions:

$$P_{D(AVE)} = 0.5 * (1.3 * BV_{DSS} * I_{AV})$$

$$E_{AS(AR)} = P_{D(AVE)} * t_{AV}$$

Where:

I_{AV} is the Allowable Current in Avalanche

 $P_{D(AVE)}$ is the Average Power Dissipation in Avalanche (Single Pulse)

t_{AV} is the Time in Avalanche

To de rate above 25 °C, at fixed I_{AV}, the following equation must be applied:

$$I_{AV} = 2 * (T_{jmax} - T_{CASE}) / (1.3 * BV_{DSS} * Z_{th})$$

Where:

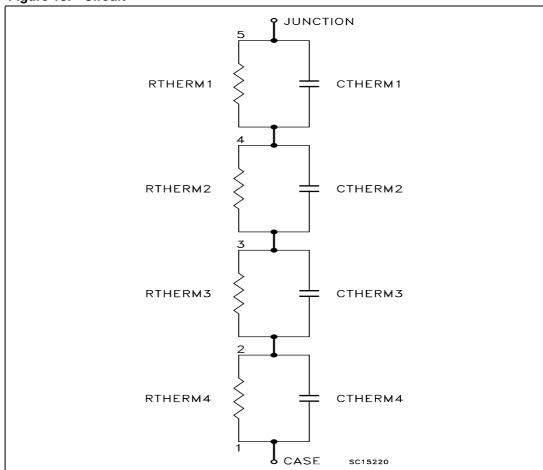
 Z_{th} = K * R_{th} is the value coming from Normalized Thermal Response at fixed pulse width equal to T_{AV} .

3 Spice thermal model

Table 6. Spice parameters

| Parameter | Node | Value |
|-----------|-------|--------|
| CTHERM1 | 5 - 4 | 0.011 |
| CTHERM2 | 4 - 3 | 0.0012 |
| CTHERM3 | 3 - 2 | 0.05 |
| CTHERM4 | 2 - 1 | 0.1 |
| | | |
| RTHERM1 | 5 - 4 | 0.09 |
| RTHERM2 | 4 - 3 | 0.02 |
| RTHERM3 | 3 - 2 | 0.11 |
| RTHERM4 | 2 - 1 | 0.17 |

Figure 18. Circuit



4 Test circuit

Figure 19. Switching times test circuit for resistive load

Figure 20. Gate charge test circuit

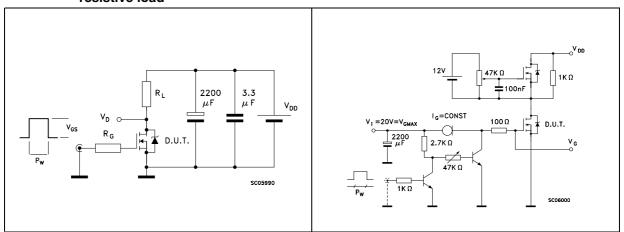


Figure 21. Test circuit for inductive load switching and diode recovery times

Figure 22. Unclamped Inductive load test circuit

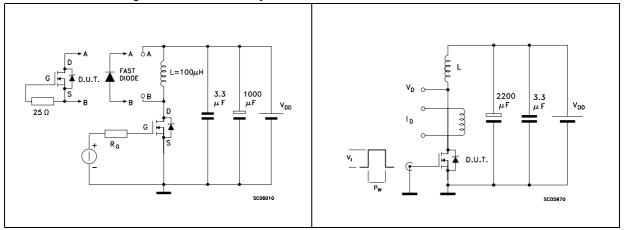
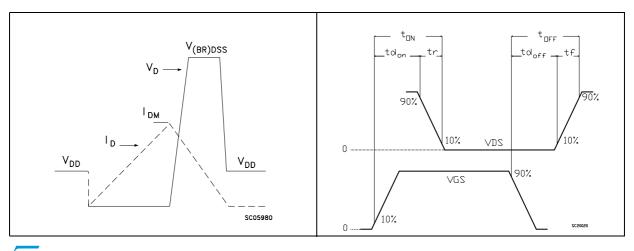


Figure 23. Unclamped inductive waveform

Figure 24. Switching time waveform



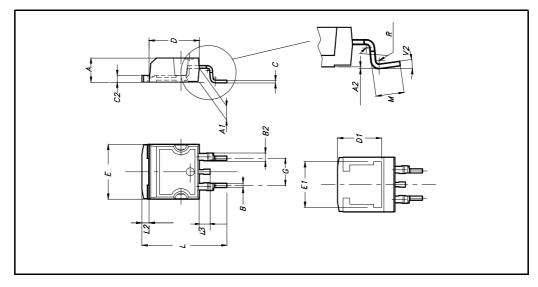
5 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com

577

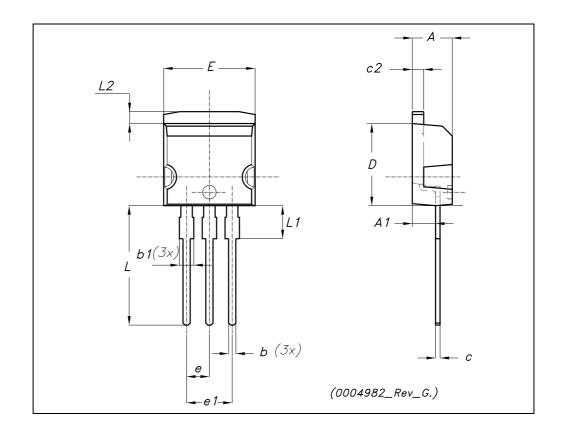
D²PAK MECHANICAL DATA

| DIM | | mm. | | | inch | | |
|------|------|-----|-------|-------|-------|-------|--|
| DIM. | MIN. | TYP | MAX. | MIN. | TYP. | MAX. | |
| Α | 4.4 | | 4.6 | 0.173 | | 0.181 | |
| A1 | 2.49 | | 2.69 | 0.098 | | 0.106 | |
| A2 | 0.03 | | 0.23 | 0.001 | | 0.009 | |
| В | 0.7 | | 0.93 | 0.027 | | 0.036 | |
| B2 | 1.14 | | 1.7 | 0.044 | | 0.067 | |
| С | 0.45 | | 0.6 | 0.017 | | 0.023 | |
| C2 | 1.23 | | 1.36 | 0.048 | | 0.053 | |
| D | 8.95 | | 9.35 | 0.352 | | 0.368 | |
| D1 | | 8 | | | 0.315 | | |
| E | 10 | | 10.4 | 0.393 | | | |
| E1 | | 8.5 | | | 0.334 | | |
| G | 4.88 | | 5.28 | 0.192 | | 0.208 | |
| L | 15 | | 15.85 | 0.590 | | 0.625 | |
| L2 | 1.27 | | 1.4 | 0.050 | | 0.055 | |
| L3 | 1.4 | | 1.75 | 0.055 | | 0.068 | |
| М | 2.4 | | 3.2 | 0.094 | | 0.126 | |
| R | | 0.4 | | | 0.015 | | |
| V2 | 0º | | 4º | | | | |



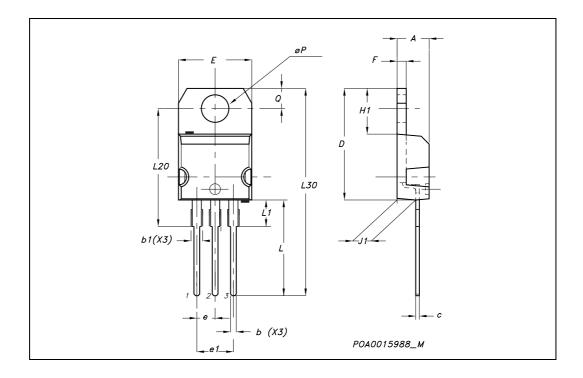
TO-262 (I²PAK) MECHANICAL DATA

| DIM | | mm. | | | inch | | |
|------|------|-----|-------|-------|------|-------|--|
| DIM. | MIN. | TYP | MAX. | MIN. | TYP. | MAX. | |
| Α | 4.40 | | 4.60 | 0.173 | | 0.181 | |
| A1 | 2.40 | | 2.72 | 0.094 | | 0.107 | |
| b | 0.61 | | 0.88 | 0.024 | | 0.034 | |
| b1 | 1.14 | | 1.70 | 0.044 | | 0.066 | |
| С | 0.49 | | 0.70 | 0.019 | | 0.027 | |
| c2 | 1.23 | | 1.32 | 0.048 | | 0.052 | |
| D | 8.95 | | 9.35 | 0.352 | | 0.368 | |
| е | 2.40 | | 2.70 | 0.094 | | 0.106 | |
| e1 | 4.95 | | 5.15 | 0.194 | | 0.202 | |
| E | 10 | | 10.40 | 0.393 | | 0.410 | |
| L | 13 | | 14 | 0.511 | | 0.551 | |
| L1 | 3.50 | | 3.93 | 0.137 | | 0.154 | |
| L2 | 1.27 | | 1.40 | 0.050 | | 0.055 | |



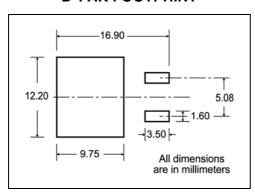
TO-220 MECHANICAL DATA

| DIM | | mm. | | | inch | | |
|------|-------|-------|-------|-------|-------|-------|--|
| DIM. | MIN. | TYP | MAX. | MIN. | TYP. | MAX. | |
| Α | 4.40 | | 4.60 | 0.173 | | 0.181 | |
| b | 0.61 | | 0.88 | 0.024 | | 0.034 | |
| b1 | 1.15 | | 1.70 | 0.045 | | 0.066 | |
| С | 0.49 | | 0.70 | 0.019 | | 0.027 | |
| D | 15.25 | | 15.75 | 0.60 | | 0.620 | |
| E | 10 | | 10.40 | 0.393 | | 0.409 | |
| е | 2.40 | | 2.70 | 0.094 | | 0.106 | |
| e1 | 4.95 | | 5.15 | 0.194 | | 0.202 | |
| F | 1.23 | | 1.32 | 0.048 | | 0.052 | |
| H1 | 6.20 | | 6.60 | 0.244 | | 0.256 | |
| J1 | 2.40 | | 2.72 | 0.094 | | 0.107 | |
| L | 13 | | 14 | 0.511 | | 0.551 | |
| L1 | 3.50 | | 3.93 | 0.137 | | 0.154 | |
| L20 | | 16.40 | | | 0.645 | | |
| L30 | | 28.90 | | | 1.137 | | |
| øΡ | 3.75 | | 3.85 | 0.147 | | 0.151 | |
| Q | 2.65 | | 2.95 | 0.104 | | 0.116 | |

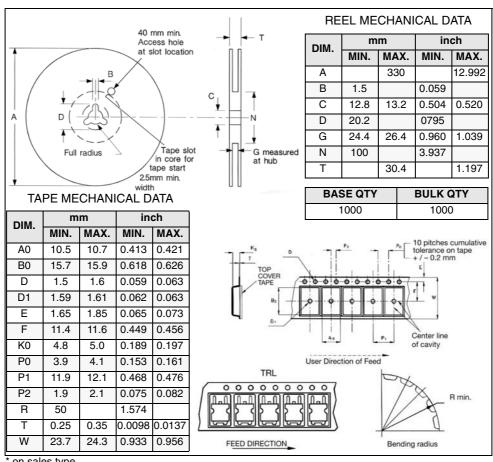


Packaging mechanical data 6

D²PAK FOOTPRINT



TAPE AND REEL SHIPMENT



on sales type

7 Revision history

Table 7. Revision history

| Date | Revision | Changes |
|-------------|----------|---------------------------------|
| 09-Sep-2004 | 2 | Complete version |
| 09-Aug-2006 | 3 | New template, no content change |

577

Please Read Carefully:

Information in this document is provided solely in connection with ST products. STMicroelectronics NV and its subsidiaries ("ST") reserve the right to make changes, corrections, modifications or improvements, to this document, and the products and services described herein at any time, without notice.

All ST products are sold pursuant to ST's terms and conditions of sale.

Purchasers are solely responsible for the choice, selection and use of the ST products and services described herein, and ST assumes no liability whatsoever relating to the choice, selection or use of the ST products and services described herein.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted under this document. If any part of this document refers to any third party products or services it shall not be deemed a license grant by ST for the use of such third party products or services, or any intellectual property contained therein or considered as a warranty covering the use in any manner whatsoever of such third party products or services or any intellectual property contained therein.

UNLESS OTHERWISE SET FORTH IN ST'S TERMS AND CONDITIONS OF SALE ST DISCLAIMS ANY EXPRESS OR IMPLIED WARRANTY WITH RESPECT TO THE USE AND/OR SALE OF ST PRODUCTS INCLUDING WITHOUT LIMITATION IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION), OR INFRINGEMENT OF ANY PATENT, COPYRIGHT OR OTHER INTELLECTUAL PROPERTY RIGHT.

UNLESS EXPRESSLY APPROVED IN WRITING BY AN AUTHORIZED ST REPRESENTATIVE, ST PRODUCTS ARE NOT RECOMMENDED, AUTHORIZED OR WARRANTED FOR USE IN MILITARY, AIR CRAFT, SPACE, LIFE SAVING, OR LIFE SUSTAINING APPLICATIONS, NOR IN PRODUCTS OR SYSTEMS WHERE FAILURE OR MALFUNCTION MAY RESULT IN PERSONAL INJURY, DEATH, OR SEVERE PROPERTY OR ENVIRONMENTAL DAMAGE. ST PRODUCTS WHICH ARE NOT SPECIFIED AS "AUTOMOTIVE GRADE" MAY ONLY BE USED IN AUTOMOTIVE APPLICATIONS AT USER'S OWN RISK.

Resale of ST products with provisions different from the statements and/or technical features set forth in this document shall immediately void any warranty granted by ST for the ST product or service described herein and shall not create or extend in any manner whatsoever, any liability of ST.

ST and the ST logo are trademarks or registered trademarks of ST in various countries.

Information in this document supersedes and replaces all information previously supplied.

The ST logo is a registered trademark of STMicroelectronics. All other names are the property of their respective owners.

© 2007 STMicroelectronics - All rights reserved

STMicroelectronics group of companies

Australia - Belgium - Brazil - Canada - China - Czech Republic - Finland - France - Germany - Hong Kong - India - Israel - Italy - Japan - Malaysia - Malta - Morocco - Singapore - Spain - Sweden - Switzerland - United Kingdom - United States of America

www.st.com

477